

MOSFET Maximum Ratings T₁ = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V _{DSS}	Drain to Source Voltage		40	V
V _{GS}	Gate to Source Voltage		±20	V
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	50	•
I _D	Pulsed Drain Current	T _C = 25°C	See Figure4	— A
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	40	mJ
P _D	Power Dissipation		75	W
	Derate Above 25°C		0.5	W/ ^o C
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C
R _{0JC}	Thermal Resistance Junction to Case		2	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance Junction to Ambient	(Note 3)	52	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD9410	FDD9410_F085	D-PAK(TO-252)	13"	12mm	2500 units

Notes:

1: Current is limited by bondwire configuration.

2: Starting T_J = 25°C, L = 500H, I_{AS} = 40A, V_{DD} = 40V during inductor charging and V_{DD} = 0V during time in avalanche. 3: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder ⁴⁰⁷ mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Symbol	Parameter	Test C	Conditions	Min	Тур	Max	Units
Off Cha	racteristics						
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _G	_{SS} = 0V	40	-	-	V
	Drain to Source Leakage Current	V _{DS} = 40V,	$T_J = 25^{\circ}C$	-	-	1	μA
IDSS		$V_{GS} = 0V$	T _J = 175 ^o C(Note 4)	-	-	1	mA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
(DS(OD)	Drain to Source On Resistance	I _D = 50A,		-	3.5	4.1	mΩ
r _{DS(on)}			$T_{\rm J} = 175^{\circ} C(\text{Note 4})$		6.1	7.1	mΩ
Dynami _{C_{iss}}	c Characteristics			_	1715	_	pF
C _{oss}	Output Capacitance	– V _{DS} = 25V, V _G	_{iS} = 0V,	-	453	-	pF
C _{rss}	Reverse Transfer Capacitance	f = 1MHz		-	28	-	pF
R _g	Gate Resistance	f = 1MHz		-	2.3	-	Ω
Q _{g(ToT)}	Total Gate Charge at 10V	V _{GS} = 0 to 10V	/ V _{DD} = 20V	-	23.5	34.5	nC
Q _{g(th)}	Threshold Gate Charge	V_{GS} = 0 to 2V	$I_{\rm D} = 50{\rm A}$	-	3.2	4	nC
Q _{gs}	Gate to Source Gate Charge			-	9.6	-	nC
<u>^</u>	Cata ta Drain "Millar" Charge				4.4		~^

FDD9410_F085 N-Channel Power Trench[®] MOSFET

Switching Characteristics

Gate to Drain "Miller" Charge

t _{on}	Turn-On Time		-	-	38	ns
t _{d(on)}	Turn-On Delay Time		-	12	-	ns
t _r	Rise Time	V _{DD} = 20V, I _D = 50A, V _{GS} = 10V, R _{GEN} = 6Ω	-	12	-	ns
t _{d(off)}	Turn-Off Delay Time	V _{GS} = 10V, R _{GEN} = 6Ω	-	20	-	ns
t _f	Fall Time		-	9	-	ns
t _{off}	Turn-Off Time		-	-	45	ns

Drain-Source Diode Characteristics

V	Source to Drain Diode Voltage	I _{SD} = 50A, V _{GS} = 0V	-	-	1.25	V
V _{SD}	Source to Drain Diode Voltage	I _{SD} = 25A, V _{GS} = 0V	-	-	1.2	V
T _{rr}	Reverse Recovery Time	I _F = 50A, dI _{SD} /dt = 100A/μs,	-	44	58	ns
Q _{rr}	Reverse Recovery Charge	V _{DD} =32V	-	31.5	41	nC

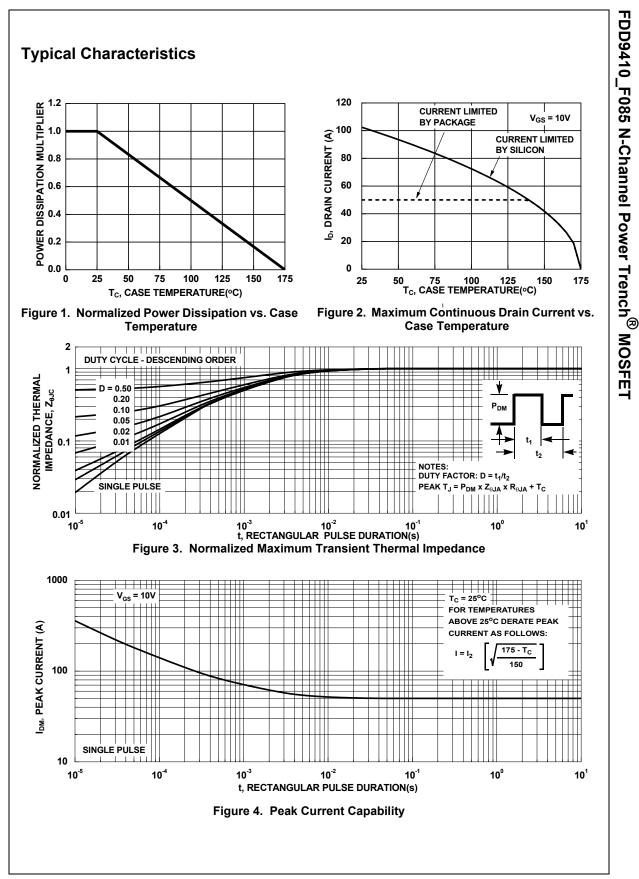
Note:

Q_{gd}

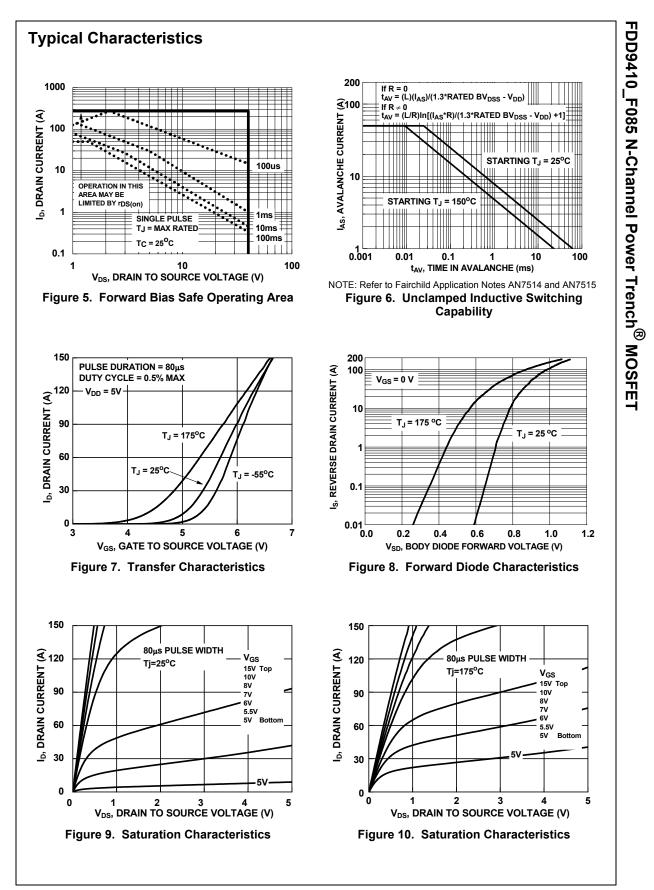
4: The maximum value is specified by design at T_J = 175°C. Product is not tested to this condition in production.

4.4

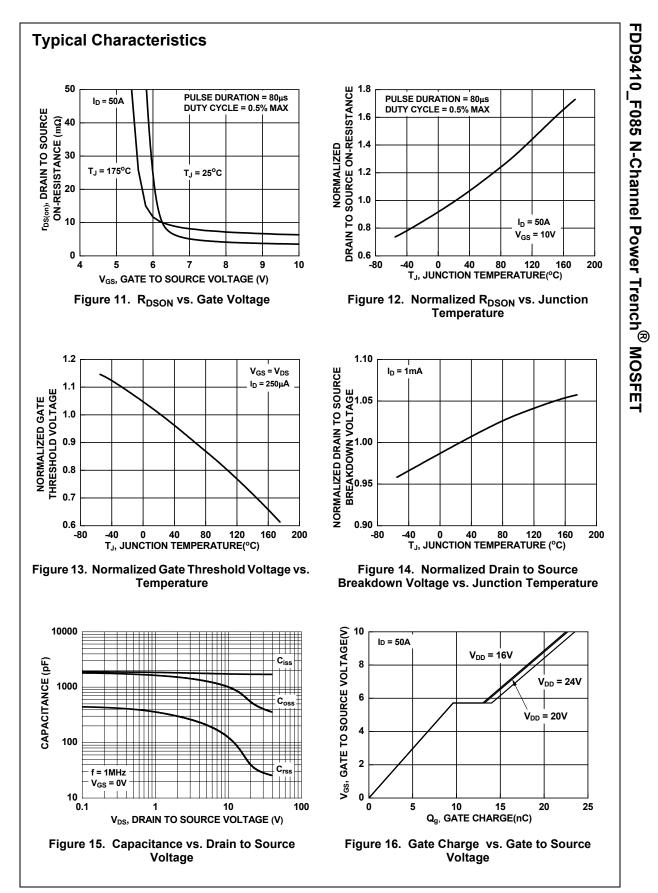
nC



FDD9410_F085 Rev. C2



FDD9410_F085 Rev. C2



FDD9410_F085 Rev. C2



Semiconductor. The datasheet is for reference information only.

Rev 171





* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT <u>HTTP://WWW.FAIRCHILDSEMI.COM</u>, FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

AUTHORIZED USE

Unless otherwise specified in this data sheet, this product is a standard commercial product and is not intended for use in applications that require extraordinary levels of quality and reliability. This product may not be used in the following applications, unless specifically approved in writing by a Fairchild officer: (1) automotive or other transportation, (2) military/aerospace, (3) any safety critical application – including life critical medical equipment – where the failure of the Fairchild product reasonably would be expected to result in personal injury, death or property damage. Customer's use of this product is subject to agreement of this Authorized Use policy. In the event of an unauthorized use of Fairchild's product, Fairchild accepts no liability in the event of product failure. In other respects, this product shall be subject to Fairchild's Worldwide Terms and Conditions of Sale, unless a separate agreement has been signed by both Parties.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Terms of Use

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms						
Datasheet Identification	Product Status	Definition				
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.				
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.				
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.				
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.				

Rev. 177

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Fairchild Semiconductor: <u>FDD9410_F085</u>